

School of Physics and Astronomy



UNIVERSITY OF LEEDS

Faculty of Engineering and Physical Sciences



A Dirac semimetal phase in topological insulator Sb_2Te_3

University of Leeds
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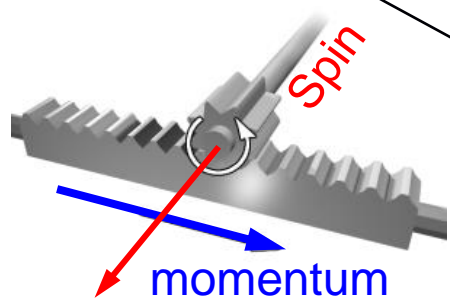
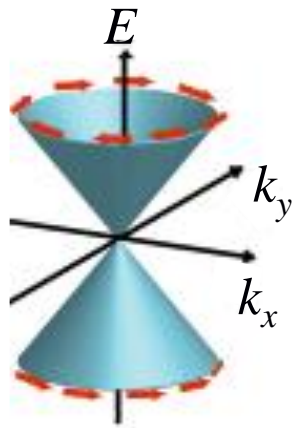


Research Interests: Topological Materials Physics



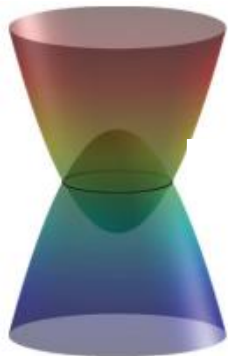
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Metallic (gapless) edge/surface Topological insulators (TI)



Spin-momentum locking

topological protection



Spin orbit interaction (SOI)

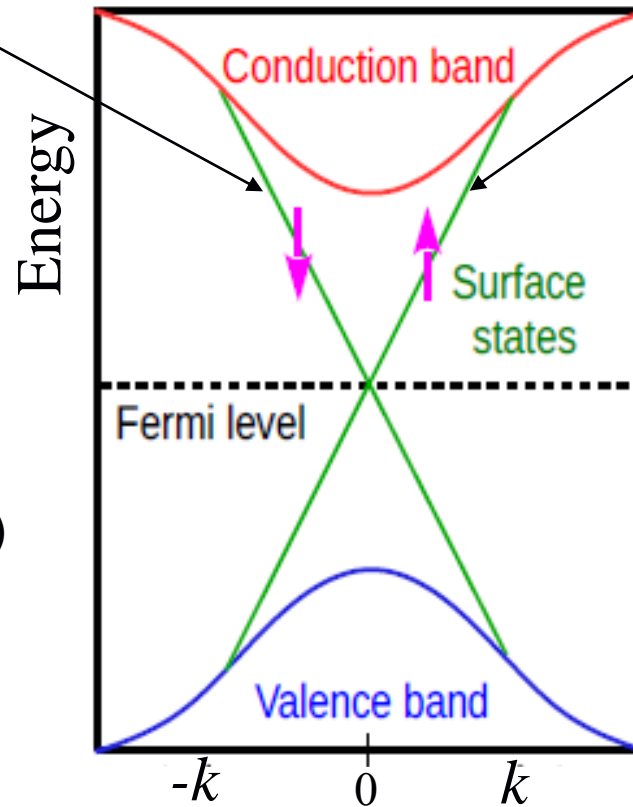


Band inversion

Kramers degeneracy

Presence of symmetries
e.g., Time/Spatial Reversal Symmetry

Electronic band structure

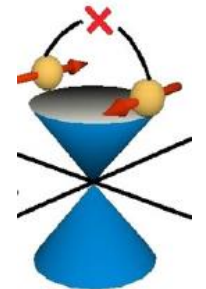
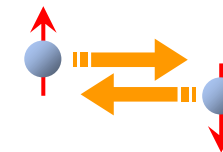


Fast response

Massless Dirac fermions
(linear energy-momentum dispersion)

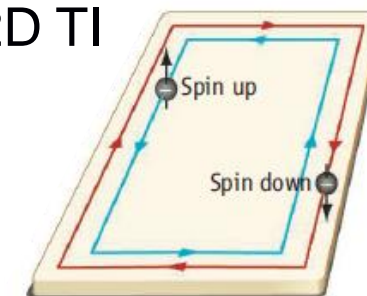
Energy saving

Pure Spin Current



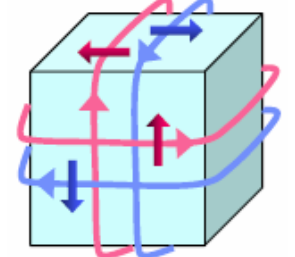
Back scattering suppression

2D TI



Quantum spin Hall system

3D TI

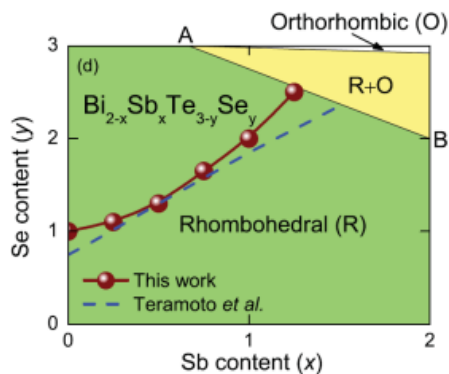


Nagaosa, Science (2007)

Research achievements



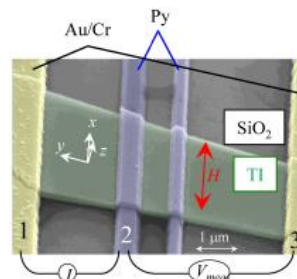
Bulk TI Surface-dominant transport



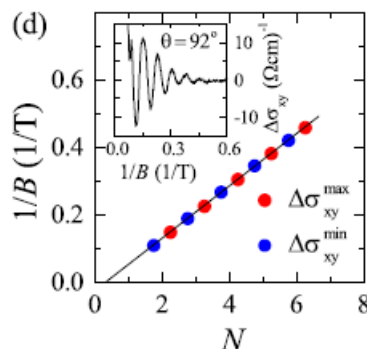
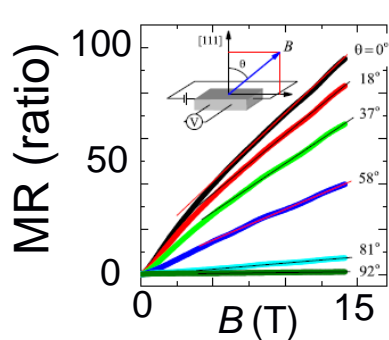
- PRB **82** (2010) 241306(R)
- PRL **107** (2011) 016801
- PRB **84** (2011) 075316
- PRB **84** (2011) 165311
- PRB **85** (2012) 155301
- PRB **86** (2012) 075306

Spin-polarized current flow

Nano Lett. **14** (2014) 6226



Bulk TSM (Dirac semimetal)



TIBiSSe

PRB **91** (2015) 041203(R)

Superconducting TIs/TCIs

Cu_xBi₂Se₃

- PRL **106** (2011) 127004
- PRB **84** (2011) 054513
- PRL **107** (2011) 217001
- PRB **86** (2012) 180505(R)
- PRB **90** (2014) 094503

Sn_{1-x}In_xTe

- PRL **109** (2012) 217004
- PRB **88** (2013) 140502(R)
- Cryst. Growth Des. **15** (2015) 2748

Cu_x(PbSe)₅(Bi₂Se₃)₆

- PRB **90** (2014) 220504(R)

Magnetic TI

Cr-TISbTe₃

- APL Mater. **3** (2015) 083302

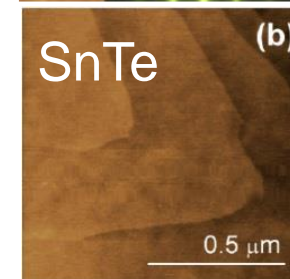
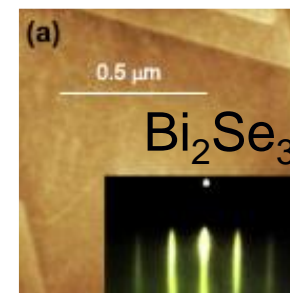
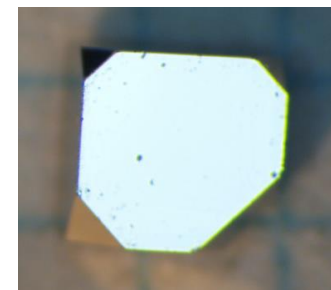
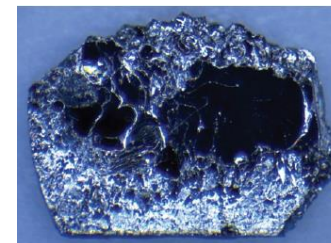
Film TI

Bi₂Se₃

- Adv. Mater. **24** (2012) 5581
- PRL **109** (2012) 066803

Bi₂Te₃/SnTe (Bi,Sb)₂Te₃

- PRB **89** (2014) 121302
- Nat. Commun. (2017) 1340
- ACS Nano **9** (2015) 4050
- APL **104** (2014) 161614

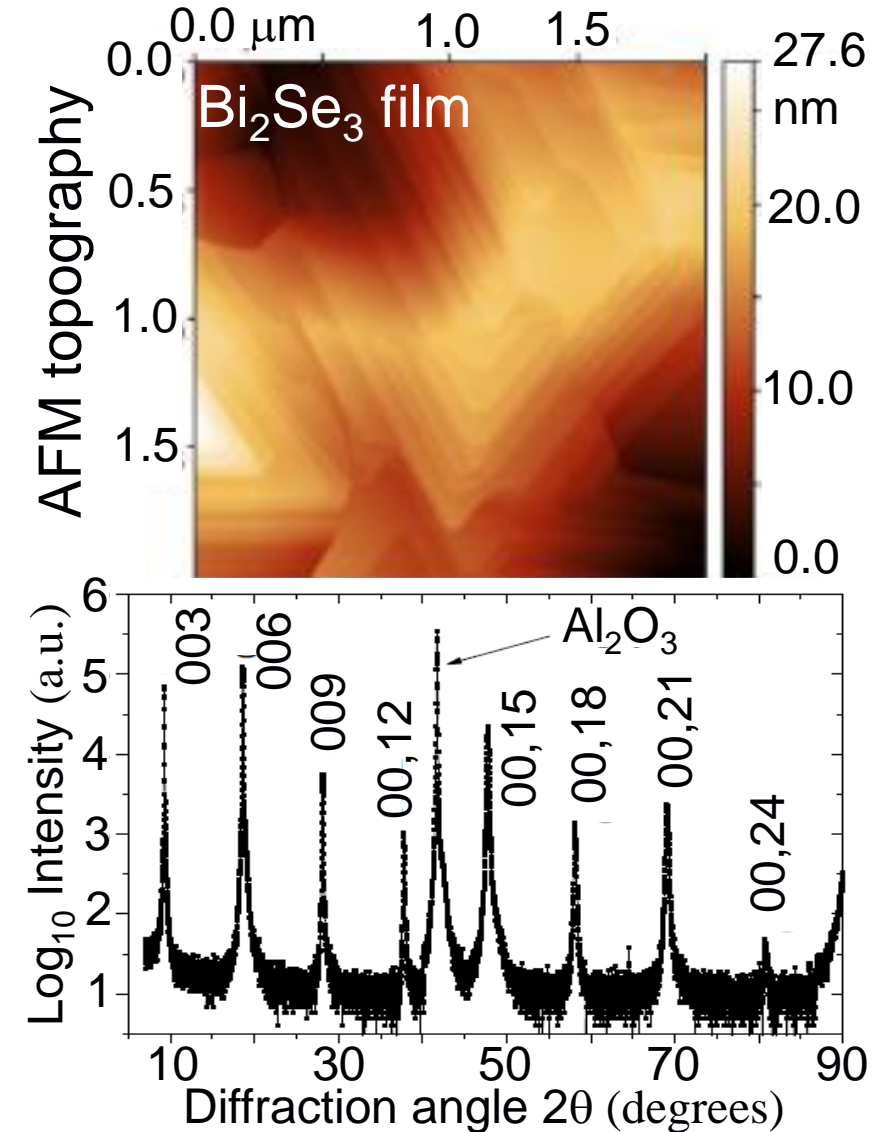
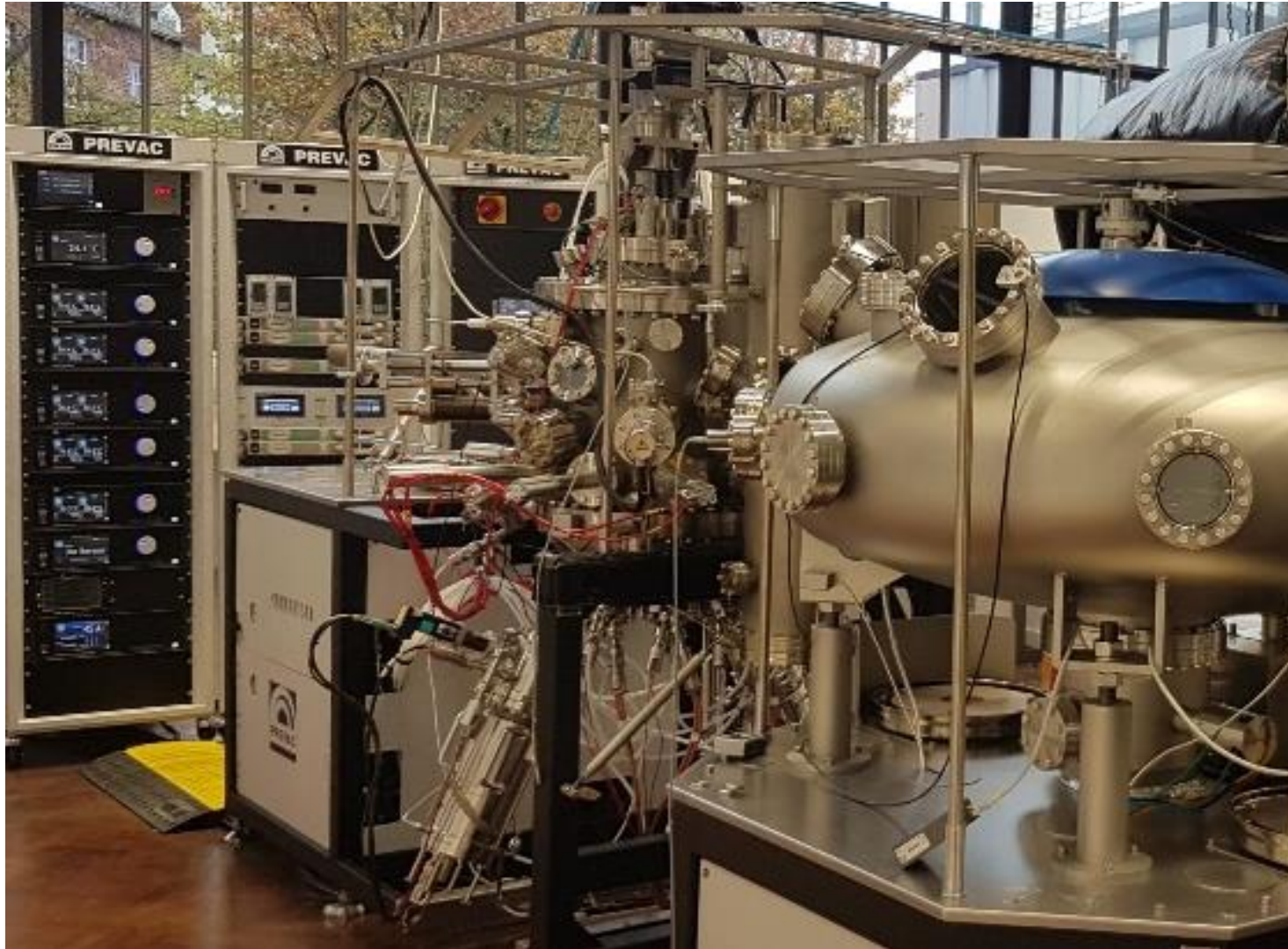


Material synthesis at Leeds: MBE thin film growth

HENRY
ROYCE
INSTITUTE



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Material synthesis at Leeds: Single crystal/Physical vapour growth



Source materials



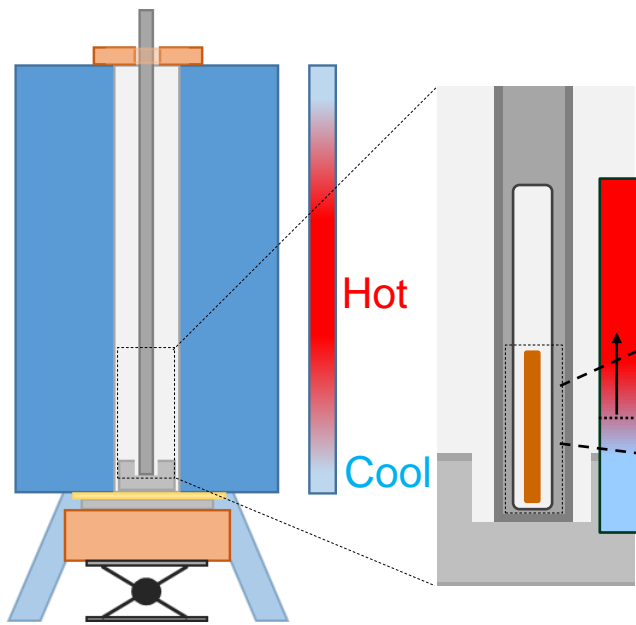
Melt growth ($T \leq 1100^\circ\text{C}$)



polycrystalline sample

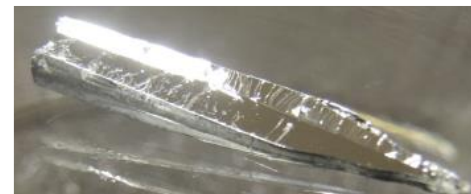


Single crystal growth



Naturally cleave planes
(Van der Waals gap)

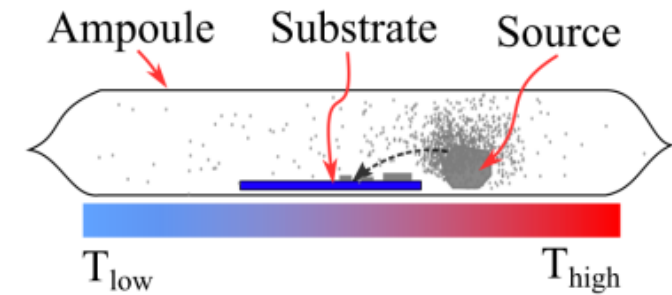
Bi_2Se_3 crystal



Doped- Sb_2Te_3 single crystal

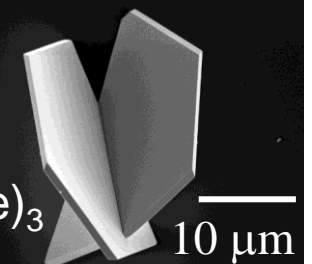


Physical Vapour Transport crystal Growth (VTG)



SEM image

$(\text{Bi,Sb})_2(\text{Te,Se})_3$



Materials synthesis & Characterisation

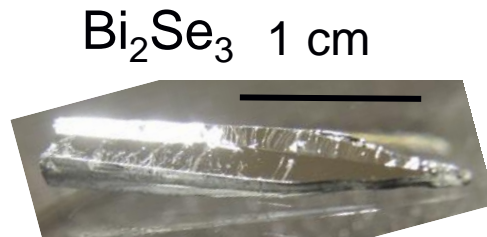
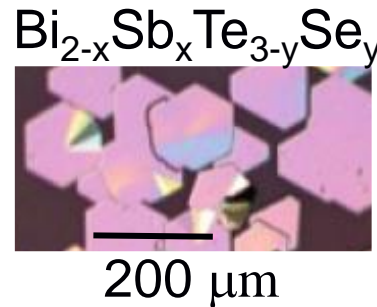
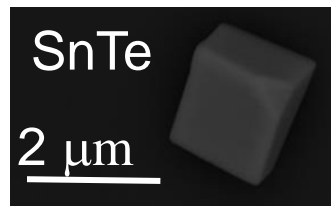
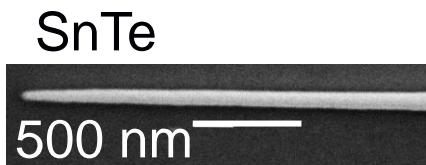


- TMs** {
- TIs** $(\text{Bi}_{1-x}\text{Sb}_x)_2\text{Te}_3$, Bi_2Te_3 , Bi_2Se_3 , $\text{Bi}_2\text{Te}_2\text{Se}$, $(\text{Bi}_{1-x}\text{Sb}_x)_2(\text{Te}_{1-y}\text{Se}_y)_3$, Sb_2Te_3
 - TCIs** SnTe , $\text{Sn}_{1-x}\text{In}_x\text{Te}$, $(\text{Pb}_{1-x}\text{Sn}_x)\text{Te}$, $(\text{Pb}_{1-x}\text{Sn}_x)\text{Se}$
 - TSMs** GeTe

Synthesis methods

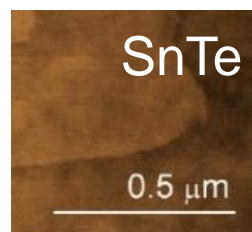
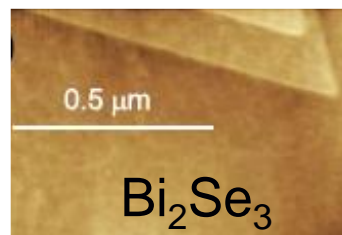
Single crystal

- Bulk (melt growth)
- Small-structures (VTG)



Epitaxial film

- Thin/ultra-thin film (UHV-MBE)



Characterisation

Crystallinity: XRD

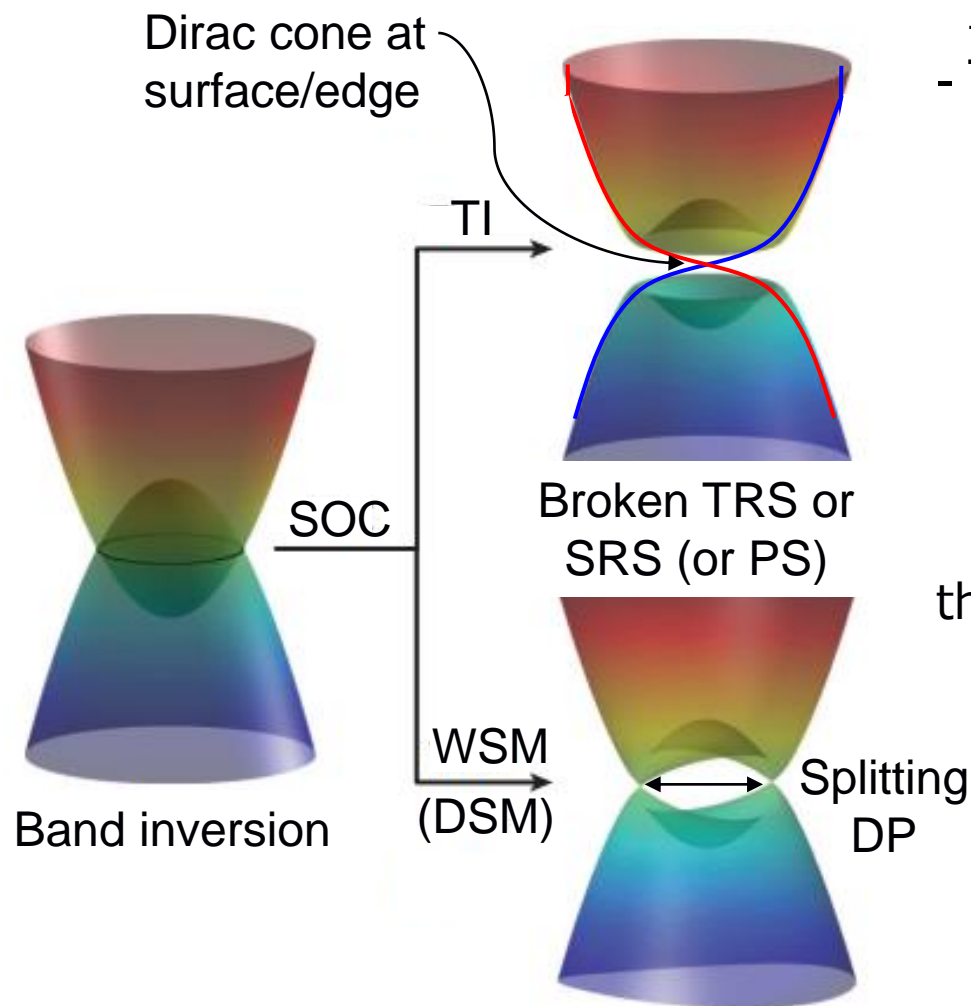
Morphology: XRR, AFM, SEM

Electrodes fabrication: vacuum-cure Ag paint (bulk), lithography in clean room (film)

Magnetoelectric properties: transport, PC spectroscopy, SQUID, scanning Hall probe, MFM

More methods and more functional devices
Collaboration

Topological Semimetals



Weyl semimetals (WSM)

- Time Reversal Symmetry (TRS) is present.

Momentum transform: $k \rightarrow -k$

Spin transform: $\sigma \rightarrow -\sigma$

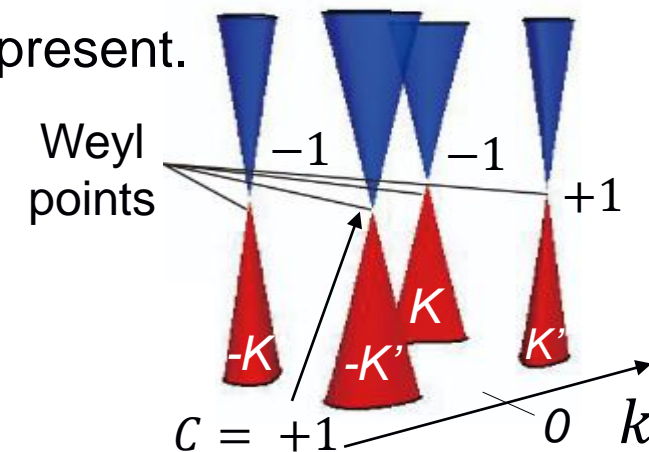
sign of Chern number C



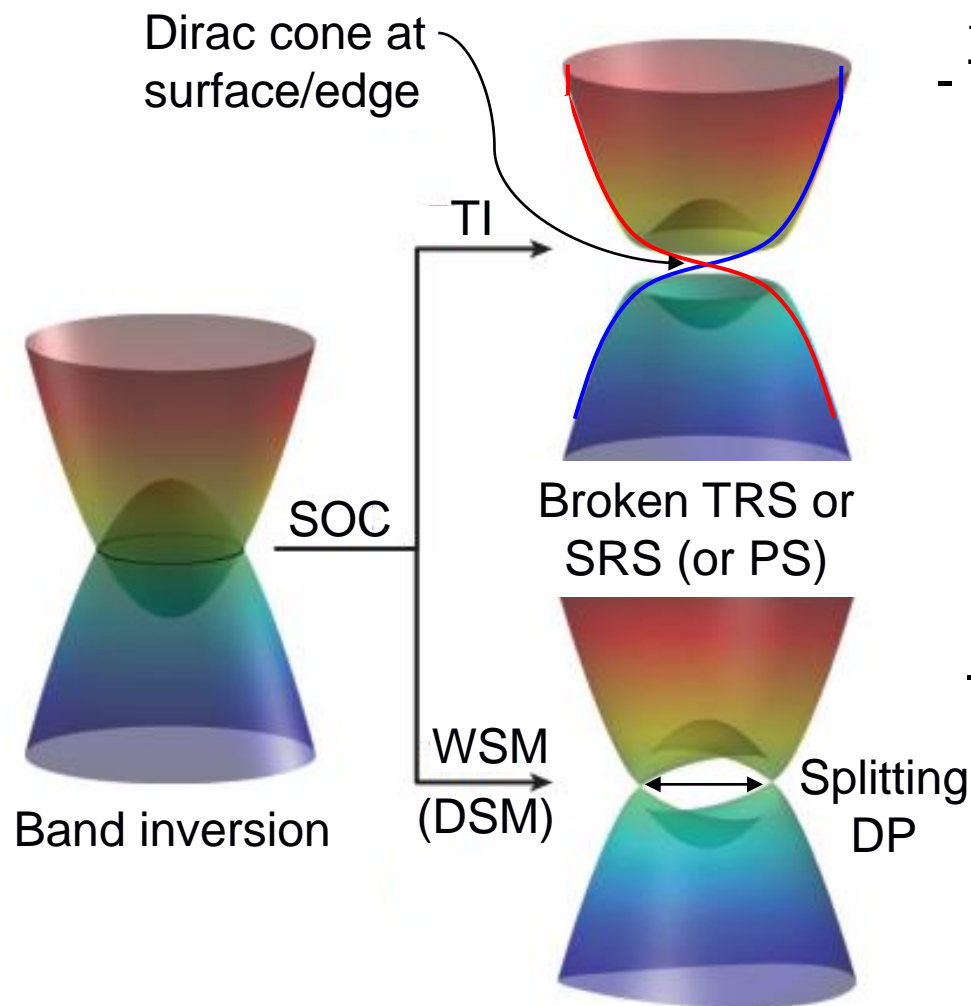
Monopole (+1) or
anti-monopole (-1)

the sum of the Chern numbers must be zero

(Nielsen-Ninomiya theorem)



Topological Semimetals



Weyl semimetals (WSM)

- Time Reversal Symmetry (TRS) is present.

Momentum transform: $k \rightarrow -k$

Spin transform: $\sigma \rightarrow -\sigma$

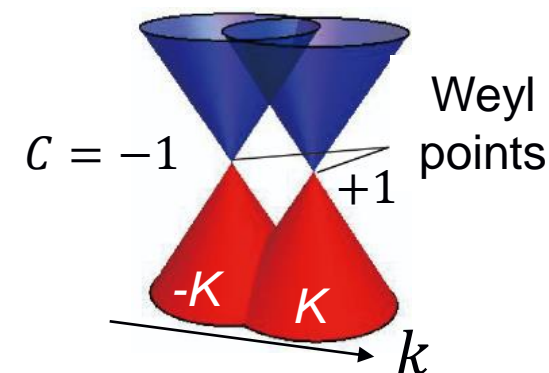
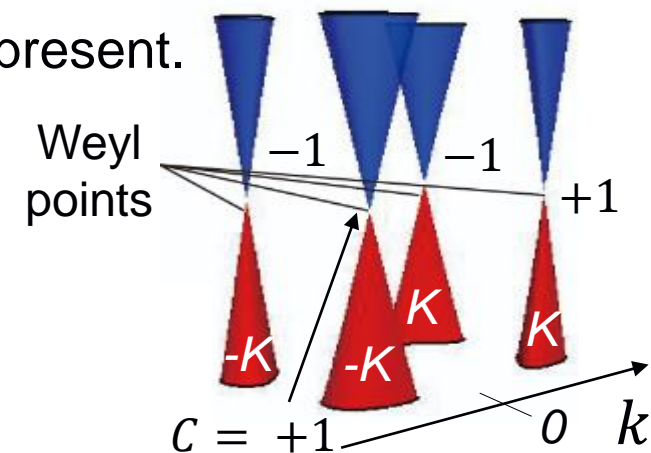
sign of Chern number C

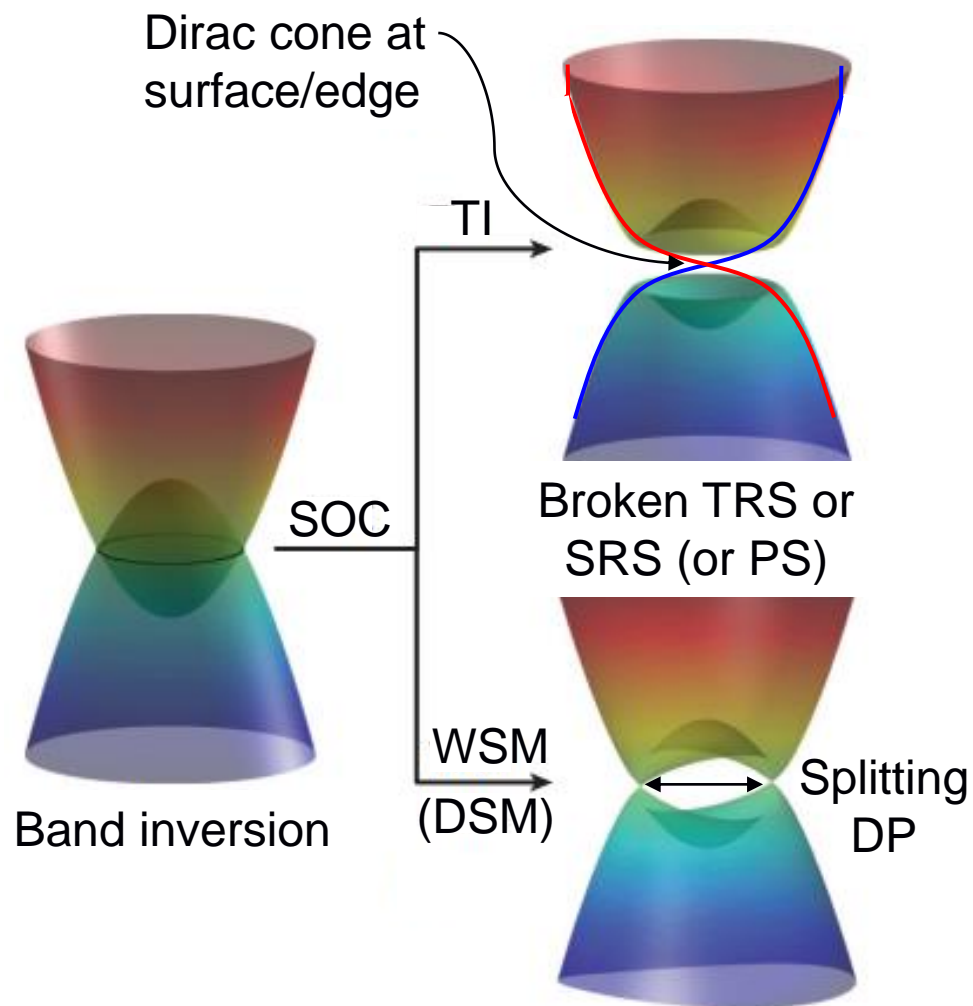


Monopole (+1) or
anti-monopole (-1)

- Spatial Reversal Symmetry (SRS) or Parity symmetry (PS) is present.

Momentum transform: $k \rightarrow -k$

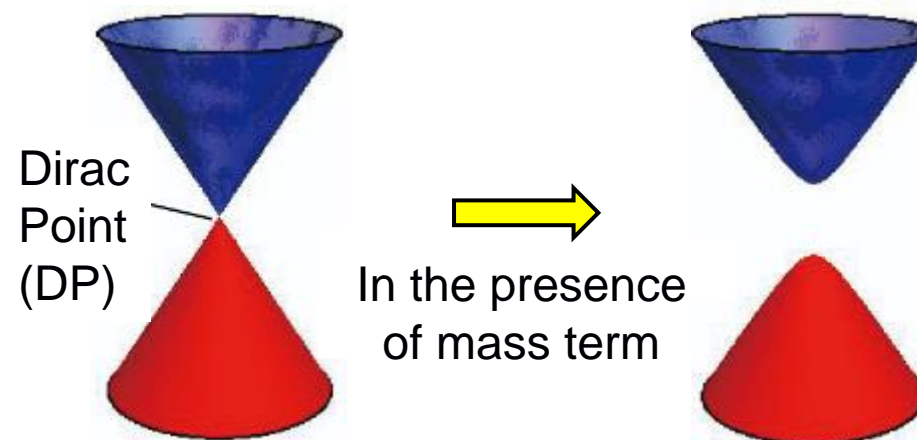




Dirac semimetals (DSM)

With TRS and SRS (PS)

NO topological protection for DPs or DNs



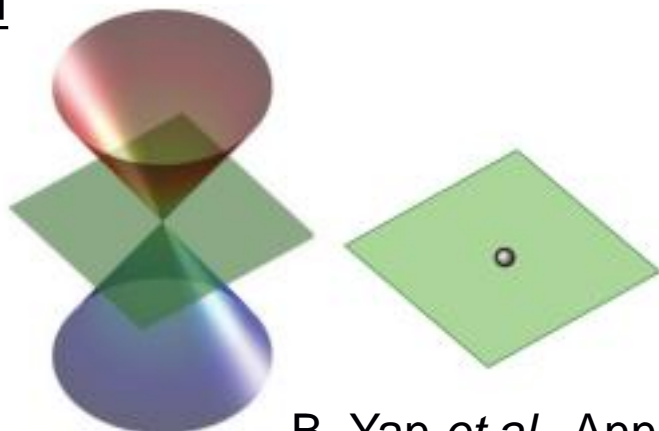
Factors for stabilising the DP(s)

- Single DP at the TRIM at the Brillouin zone boundary
- Nonsymmorphic crystal symmetry
e.g. Bi_3Na (C_3 symmetry), Cd_3As_2 (C_4 symmetry)

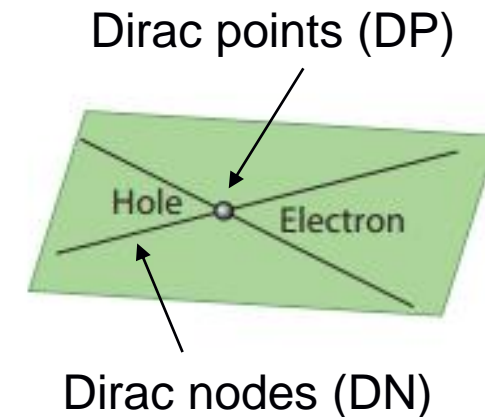
Type-I/II Weyl/Dirac semimetals



Type-I WSM

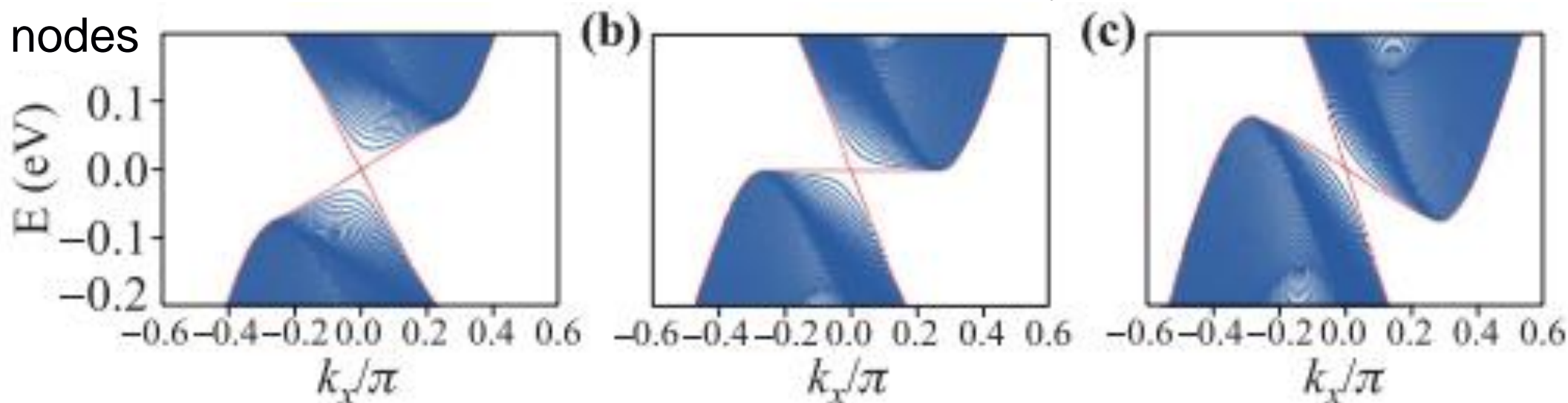


Type-II WSM



B. Yan *et al.*, Annu. Rev. Condens. Matter Phys. 2017

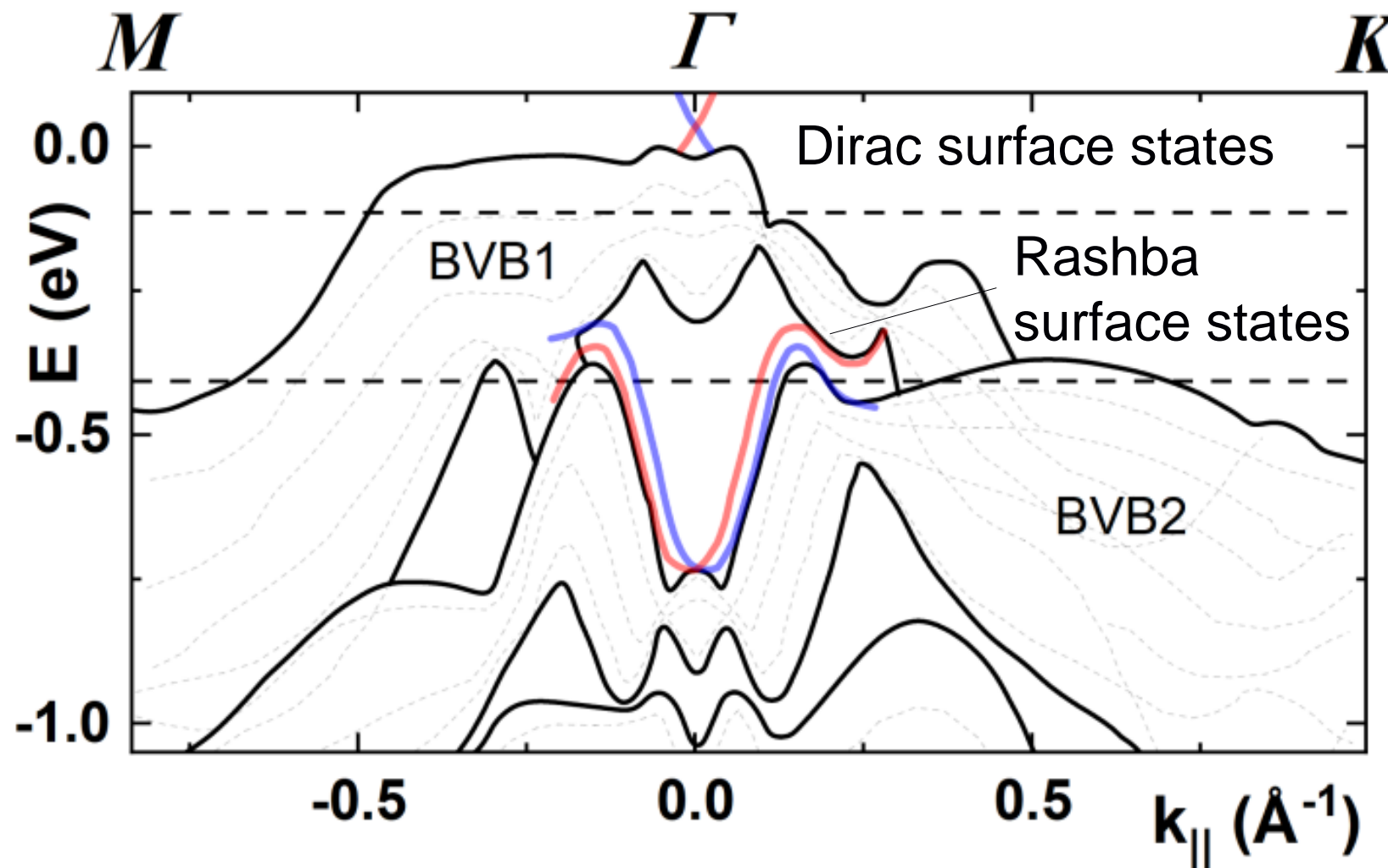
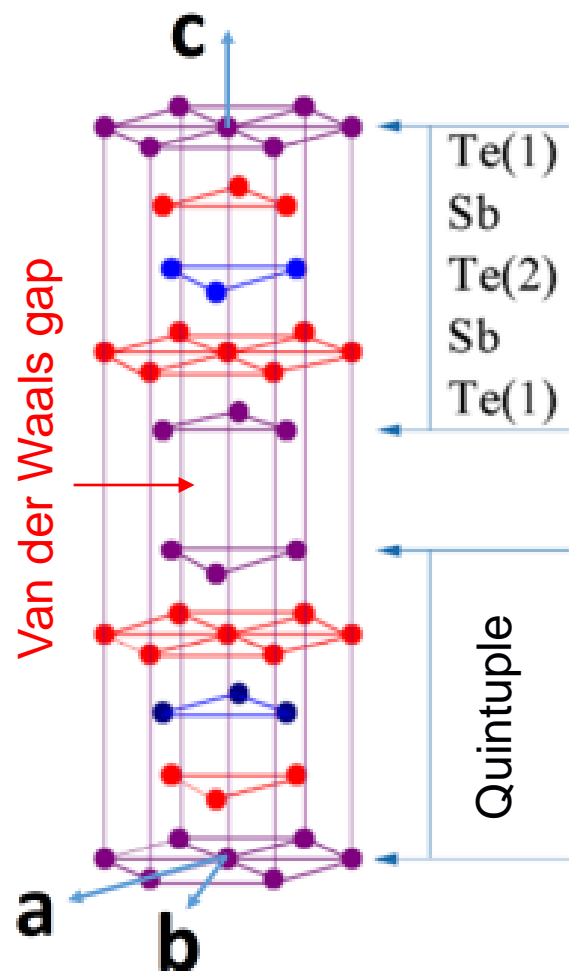
Dirac nodes



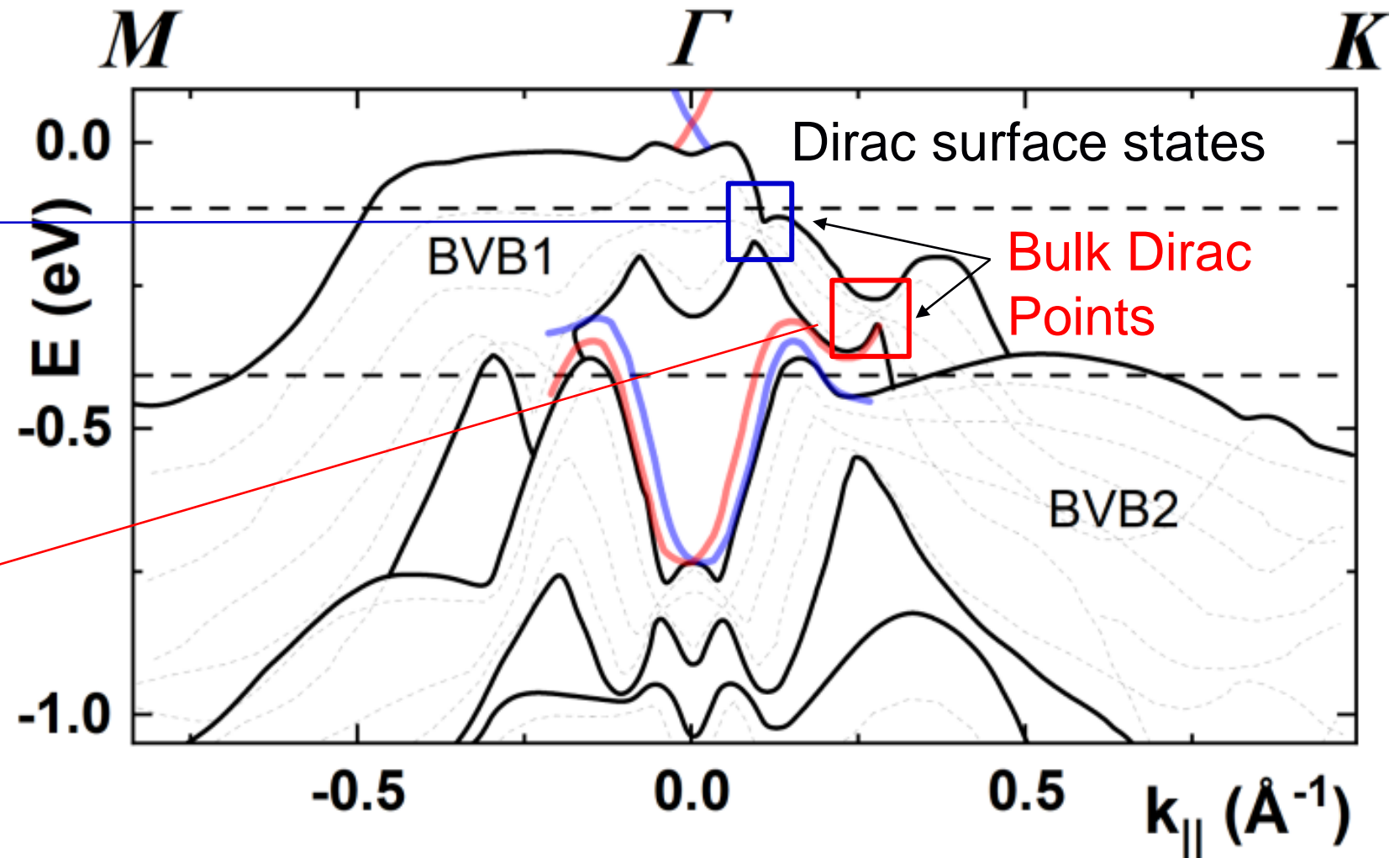
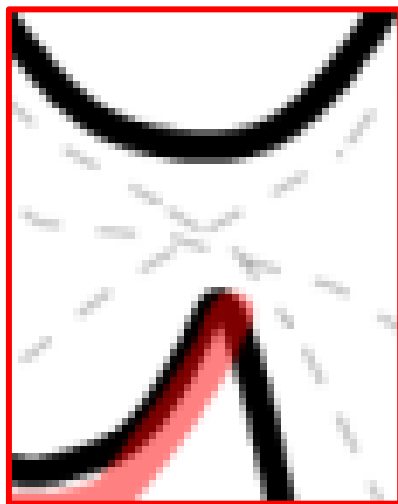
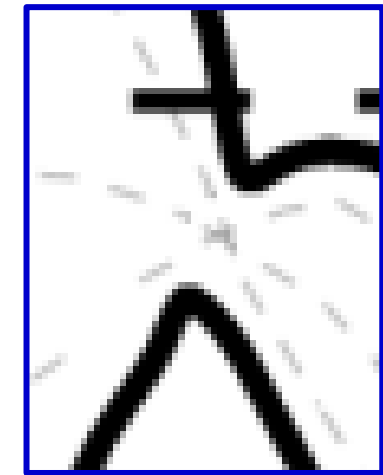
Si Li, *et al.*, Front. Phys. 2020

Well-known TI, Sb_2Te_3

Crystal structure

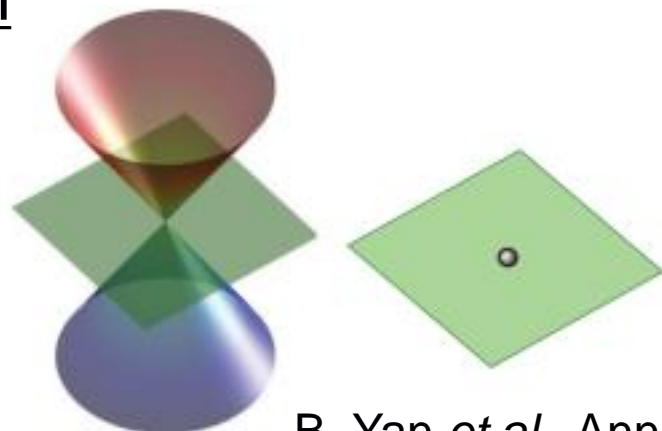


Well-known TI, Sb₂Te₃

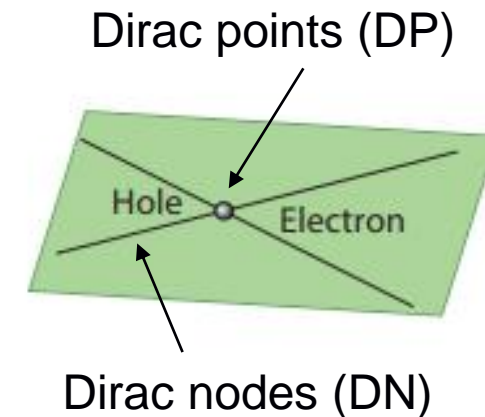


Type-I/II Weyl/Dirac semimetals

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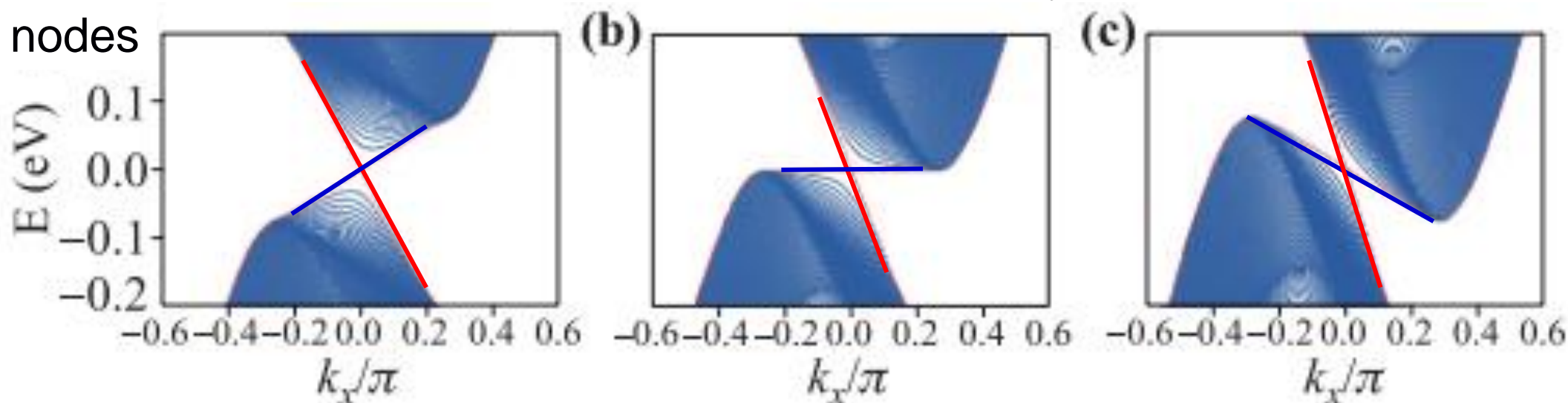


Type-II WSM



B. Yan *et al.*, Annu. Rev. Condens. Matter Phys. 2017

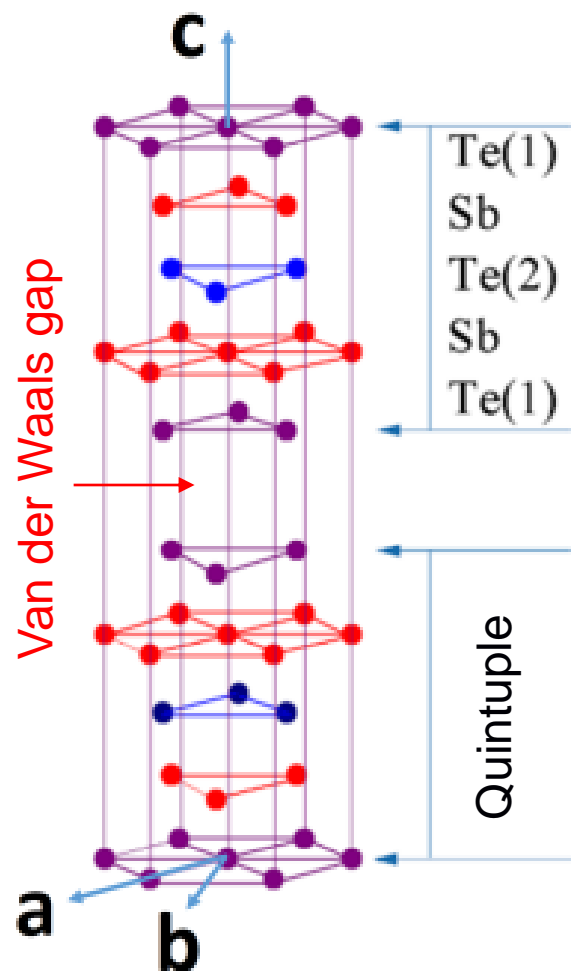
Dirac nodes



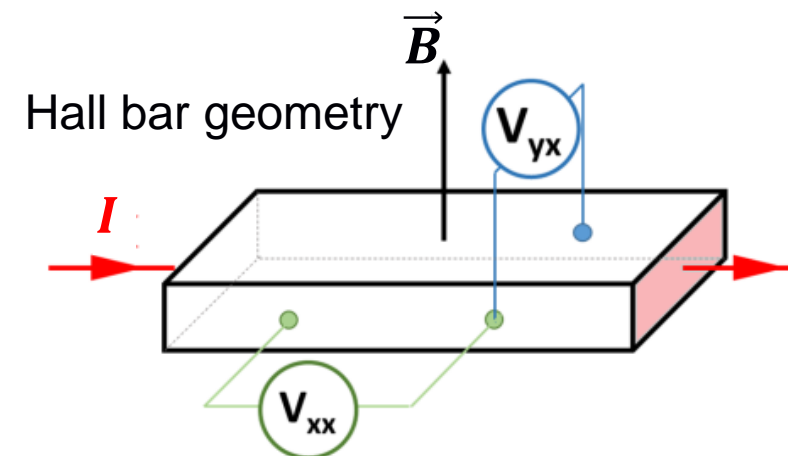
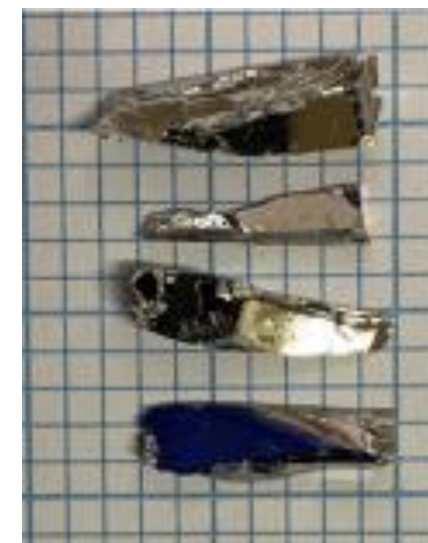
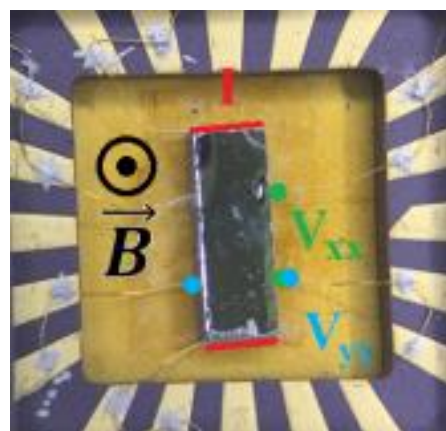
Si Li, *et al.*, Front. Phys. 2020

Self-doping Sb_2Te_3

Crystal structure



Tellurium-doped Sb_2Te_x ($x \geq 3$)



Shubnikov de Haas oscillations



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Lifshitz-Kosevich form

$$\frac{\Delta\rho_{xx}}{\rho_{xx}} \propto \cos 2\pi \left(\frac{F}{B} - \frac{1}{2} + \beta \right)$$

The extremal Fermi surface cross sectional area (CSA)

$$= F \frac{2\pi e}{\hbar}$$

$$k_F = \sqrt{\text{CSA}/\pi}$$

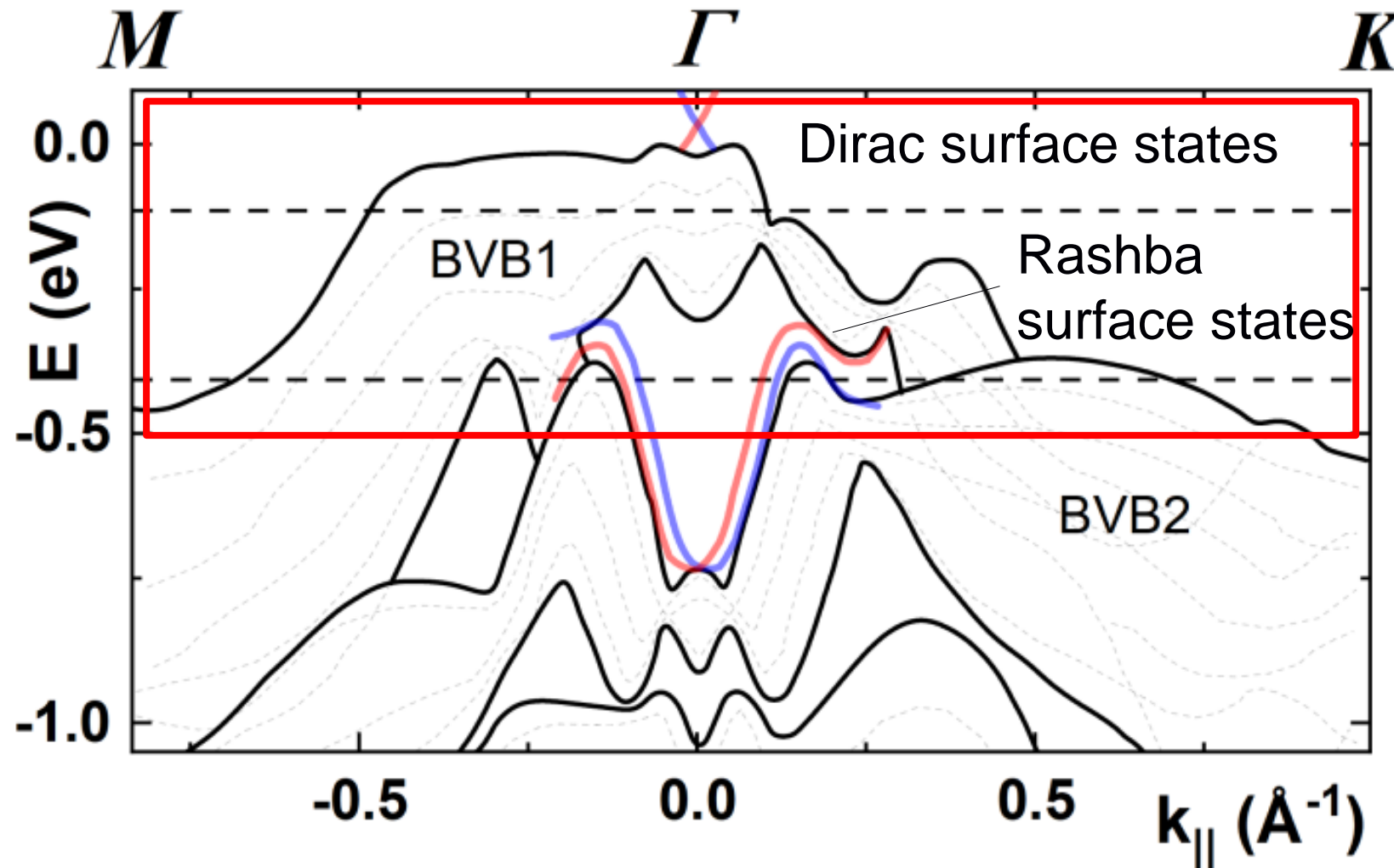
Landau level fan diagram

If $\beta = \mp(0.5 - \delta)$, e.g., $\delta \approx 1/8$

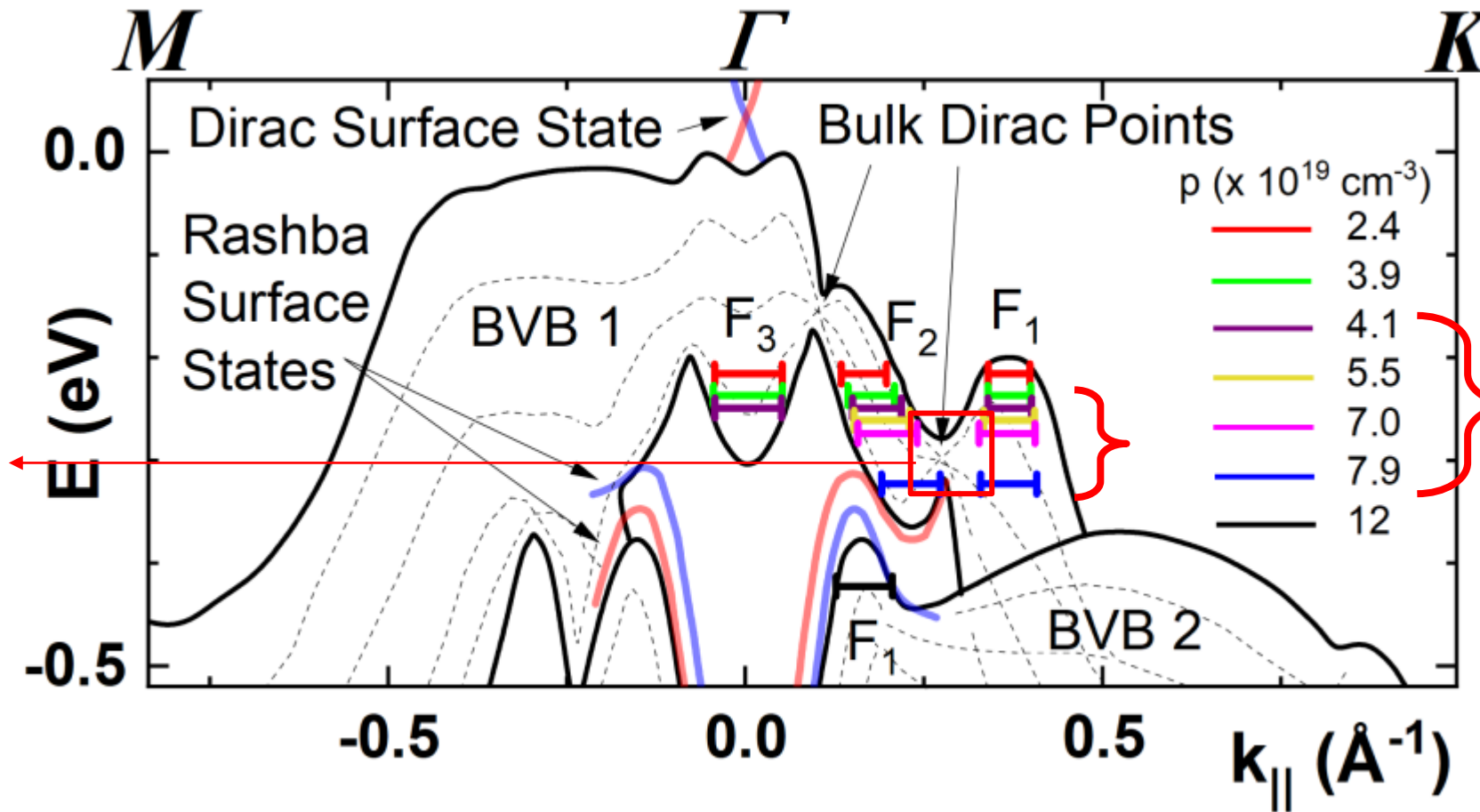
i.e., $\beta \approx \mp 0.375$, then, the system is **nontrivial**.

δ : band curvature correction

Band structure of Sb_2Te_3



Dirac semimetal phase of Sb_2Te_3



Nontrivial topology!

Bulk Dirac cones (NOT Dirac surface states) can present nontrivial topology!

- We tuned the chemical potential of single crystal Sb_2Te_3 by Te doping
- Shubnikov de Haas oscillation for single crystal Sb_2Te_3 show beats in Quantum oscillations
- Observation of Dirac semimetal phase in TI, Sb_2Te_3
- Bulk Dirac cones can provide nontrivial topology
- We are happy to collaborate with you;
we can provide topological materials thin films and single crystals.

Materials synthesis & Characterisation



- TMs {
- TIs $(\text{Bi}_{1-x}\text{Sb}_x)_2\text{Te}_3$, Bi_2Te_3 , Bi_2Se_3 , $\text{Bi}_2\text{Te}_2\text{Se}$, $(\text{Bi}_{1-x}\text{Sb}_x)_2(\text{Te}_{1-y}\text{Se}_y)_3$, Sb_2Te_3
 - TCIs SnTe , $\text{Sn}_{1-x}\text{In}_x\text{Te}$, $(\text{Pb}_{1-x}\text{Sn}_x)\text{Te}$, $(\text{Pb}_{1-x}\text{Sn}_x)\text{Se}$
 - TSMs GeTe

Synthesis methods

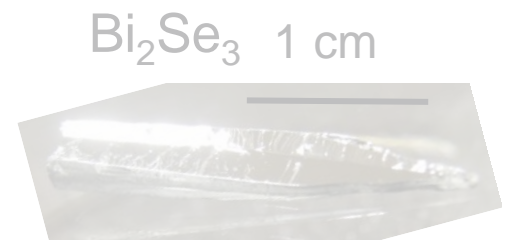
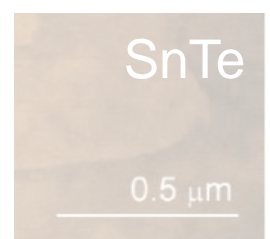
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Thank you

S.Sasaki@leeds.ac.uk